

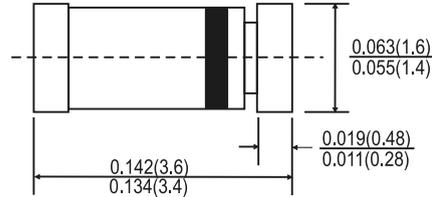


SMALL SIGNAL SWITCHING DIODE

Mini-MELF

FEATURES:

- Silicon epitaxial planar diode
- Fast switching diodes in case MINI MELF, especially suited for automatic insertion



MECHANICAL DATA

Case: MINI MELF glass case (SOD-80)  
Weight: Approx. 0.05gram

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temp. unless otherwise specified.  
Single phase, half sine wave, 60 Hz, resistive or inductive load.  
For capacitive load, derate current by 20 %.

Characteristic	Symbol	LL4148	Units
Maximum peak reverse voltage	V <sub>RRM</sub>	100	Volts
Maximum reverse voltage	V <sub>R</sub>	75	Volts
Average rectified current .half wave rectification with Resistive load at T <sub>a</sub> =25 °C And F ≥ 50HZ	I <sub>(AV)</sub>	0.15 <sup>1)</sup>	Amps
Peak forward surge current, <1S single half sine-wave auperimposed on rated load T <sub>a</sub> =25 °C	I <sub>FSM</sub>	0.5	Amps
Power dIssipation at T <sub>a</sub> =25°C	P <sub>tot</sub>	500 <sup>1)</sup>	mW
Maximum instantaneous forward voltage drop per leg at 0.01A	V <sub>F</sub>	1.0	Volts
Maximum Voltage rise when switching ON tested with 50mA pulse t=0.1, S , Rise time <30, S , f=5 to 100 KHZ	V <sub>fr</sub>	2.5	Volts
Maximum leakage current At V <sub>R</sub> =20V At V <sub>R</sub> =75V At V <sub>R</sub> =20V T <sub>a</sub> =150 °C	I <sub>R</sub>	25	nA
		5	uA
		50	uA
Maximum Reverse recovery time (Note 1)	T <sub>RR</sub>	4	ns
Maximum junction capacitance V <sub>R</sub> =V <sub>F</sub> =0V	C <sub>tot</sub>	4	pF
Maximum Thermal resistance junction to ambient	R <sub>th JA</sub>	350 <sup>1)</sup>	K /W
MINIMUM rectification efficiency at f=100MHZ , V <sub>RF</sub> =2V	η	045	
Operating temperature range	T <sub>J</sub>	150	°C
storage temperature range	T <sub>stg</sub>	-55 to +150	°C

NOTES:  
(1) Reverse recovery condition I<sub>F</sub>=0.01A , I<sub>R</sub> =0.001A , V<sub>R</sub>=6V , R<sub>L</sub> =100  
1): Valid provided that electrodes are kept at ambient temperature



RATINGS AND CHARACTERISTIC CURVES

FIG 1-FORWARD CHARACTERISTICS

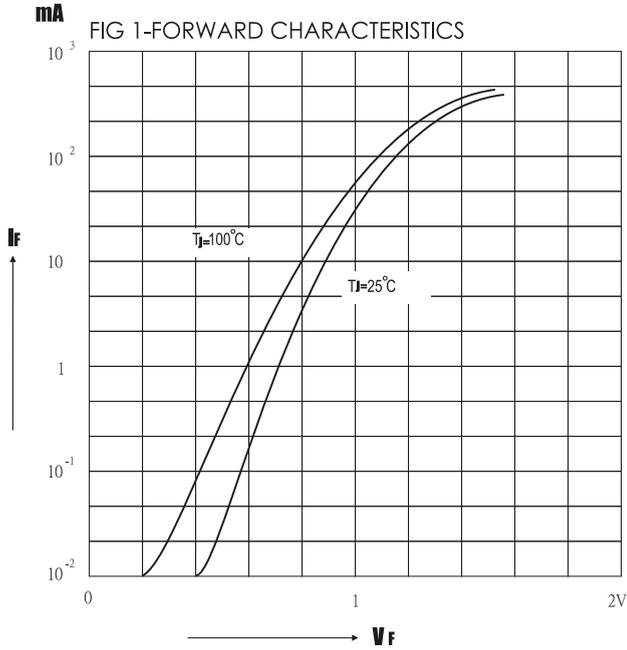


FIG 2: DYNAMIC FORWARD RESISTANCE VERSUS FORWARD CURRENT

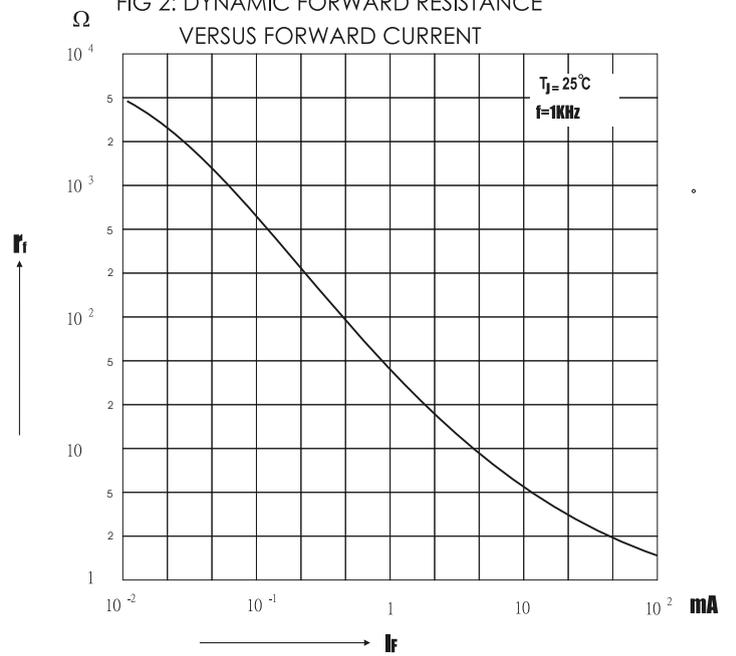


FIG 3-ADMISSIBLE POWER DISSIPATION VERSUS AMBIENT TEMPERATURE

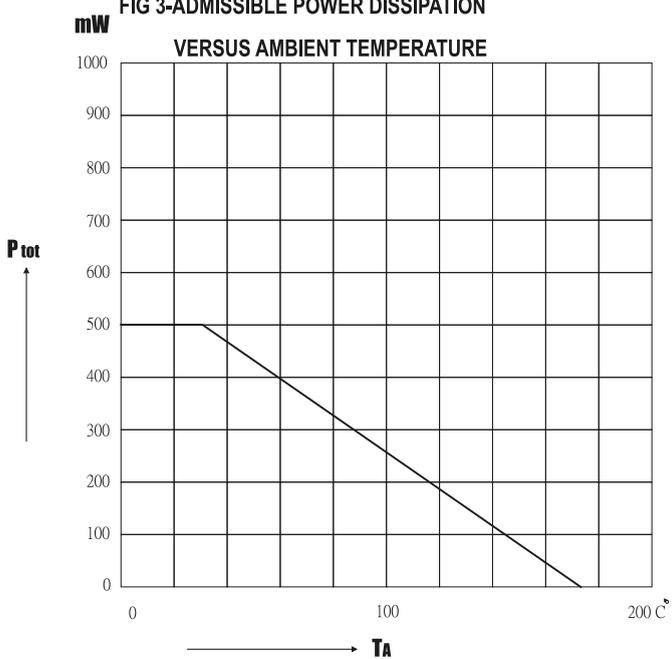
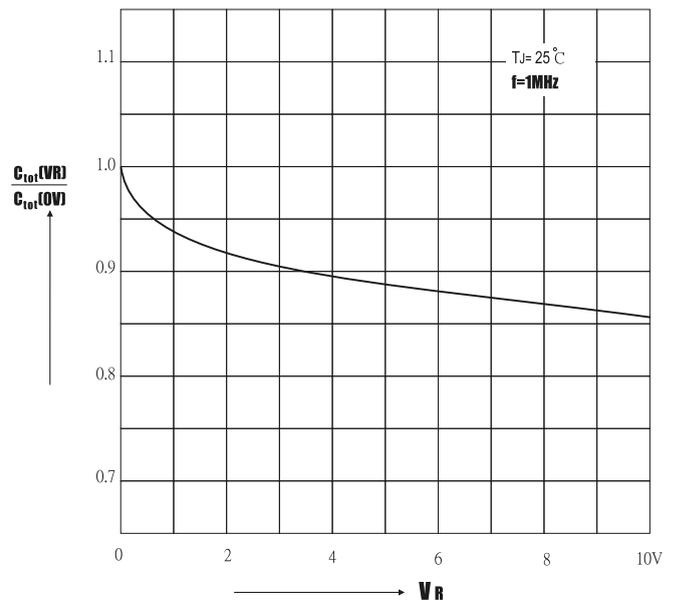


FIG. 4-RELATIVE CAPACITANCE VERSUS REVERS VOLTAGE





RATINGS AND CHARACTERISTIC CURVES

FIG.5 RECTIFICATION EFFICIENCY MEASUREMENT CIRCUIT

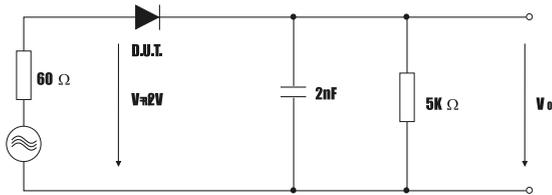


FIG 6: LEAKAGE CURRENT VERSUS JUNCTION TEMPERATURE

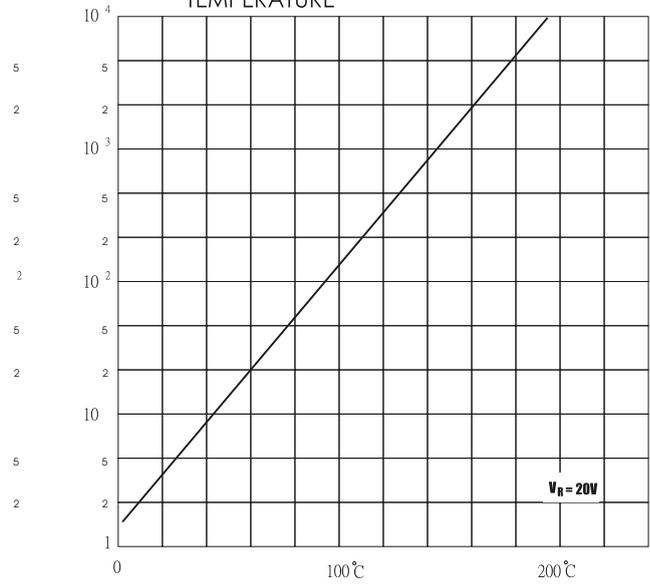
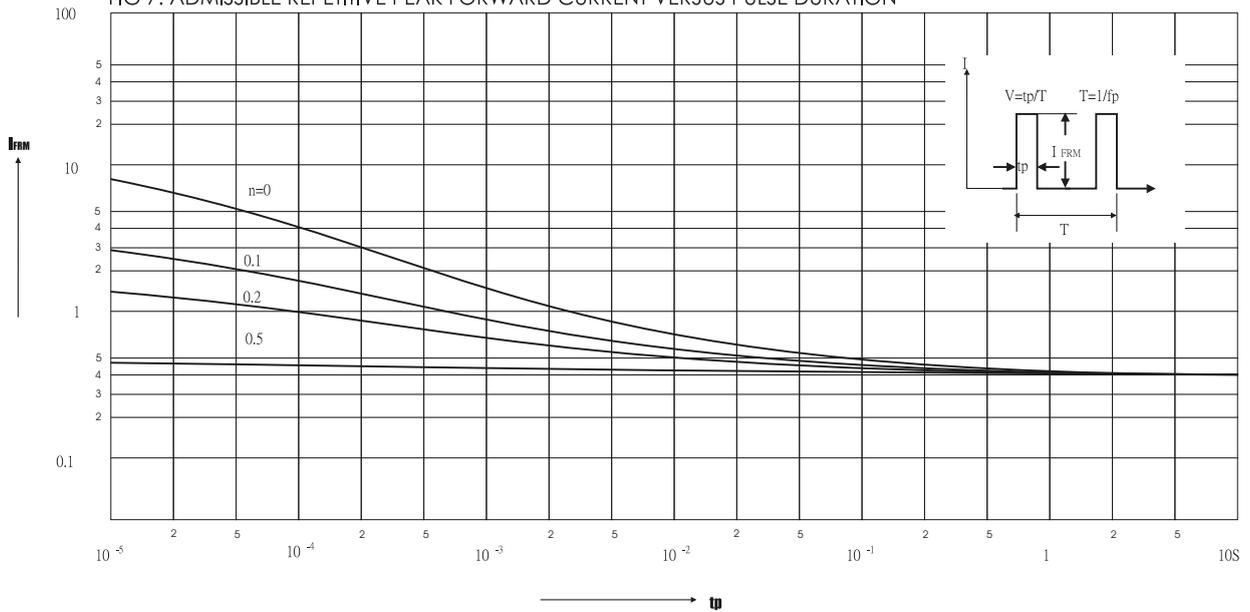


FIG 7: ADMISSIBLE REPETITIVE PEAK FORWARD CURRENT VERSUS PULSE DURATION





---

## **Disclaimer**

DACO Semiconductor reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein.

DACO Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does DACO Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

Purchasers is responsible for its products and applications using DACO Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by DACO Semiconductor. "Typical" parameters which may be provided in DACO Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts.

DACO Semiconductor products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of DACO Semiconductor's product can reasonably be expected to result in personal injury, death or severe property or environmental damage. DACO Semiconductor accept no liability for inclusion and/or use of DACO Semiconductor's products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Purchasers buy or use DACO Semiconductor products for any such unintended or unauthorized application, Purchasers shall indemnify and hold DACO Semiconductor and its suppliers and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that DACO Semiconductor was negligent regarding the design or manufacture of the part.

No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of DACO Semiconductor Co., Ltd.